NSN 5962-01-382-0172

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-382-0172

Body Length:
1.490 inches
Body Width:
0.610 inches
Body Height:
0.217 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
B-2 anitiskid control uni (acu)
Features Provided:
Burn in, mil-std-883, class b and electrostatic sensitive and monolithic and programmable and ultraviolet erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-10 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital 65, 536, uv erasable prom monolithic silicon
Voltage Rating And Type Per Characteristic:
4.5 volts total supply and 5.5 volts total supply
Memory Device Type:
Rom
Special Features:
Esd, high bite, item altered from smd 8200505ya. Used on 6005351-4, wheel board printed wiring board
Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

21 printed circuit

Terminal Type And Quantity:

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Sı	oec	ific	cati	on	Data:

67268-8200505yx government standard

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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